

SANYO Semiconductors DATA SHEET

BXL4001 — General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Motor drive.
- · Avalanche resistance guarantee.
- · 10V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		75	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	ID		85	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	340	А
Allowable Power Dissipation	D-		1.75	W
	PD	Tc=25°C	75	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		211	mJ
Avalanche Current *2	lav		51	А

Note :*1 VDD=30V, L=100 μ H, IAV=51A *2 L<100 μ H, Single pulse

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	75			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =75V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _G S=±16V, V _D S=0V			±10	μΑ

Marking: XL4001 Continued on next page.

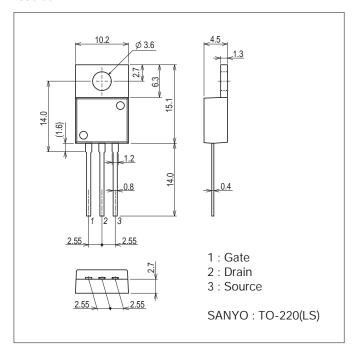
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Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	2		4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =43A		75		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=43A, VGS=10V		9.0	12.4	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		6700		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		590		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		440		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		75		ns
Rise Time	t _r	See specified Test Circuit.		340		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		260		ns
Fall Time	t _f	See specified Test Circuit.		170		ns
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =85A		115		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =85A		37		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =85A		30		nC
Diode Forward Voltage	V _{SD}	I _S =85A, V _{GS} =0V		1.0	1.5	V

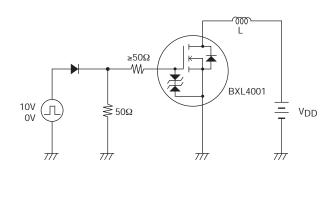
Package Dimensions

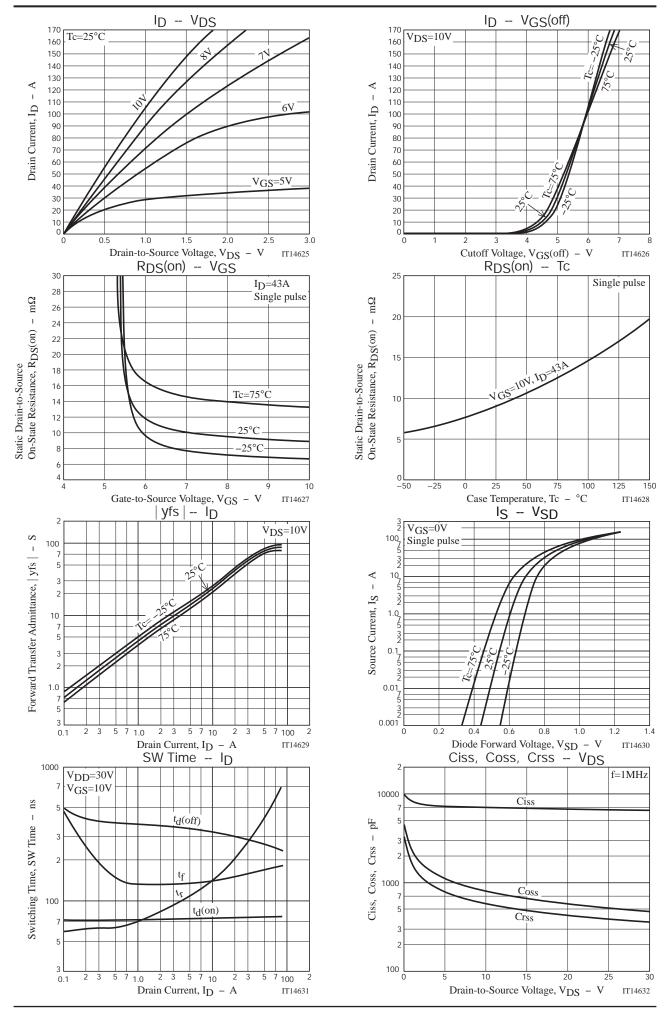
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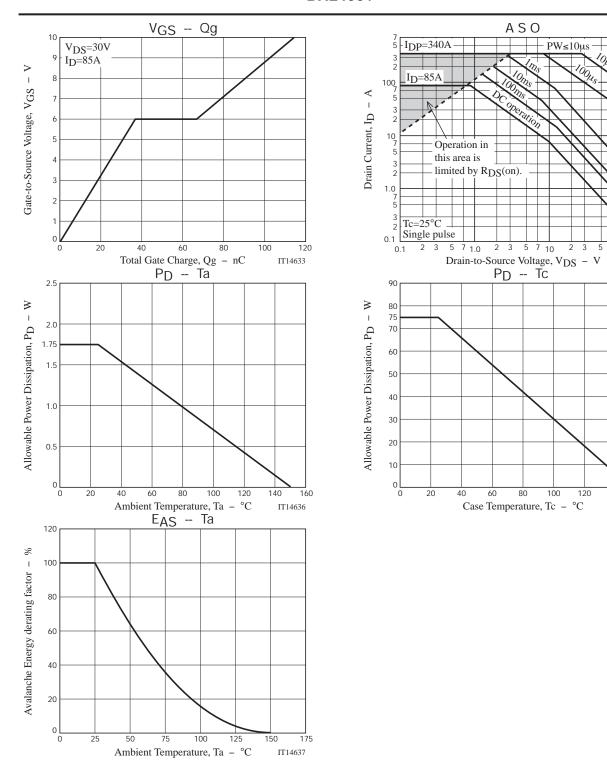


Switching Time Test Circuit

Avalanche Resistance Test Circuit







IT14634

140

160

IT14635

Note on usage: Since the BXL4001 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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